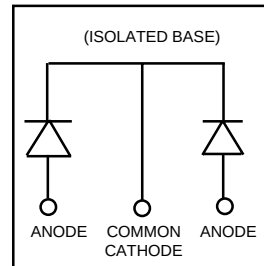


Features

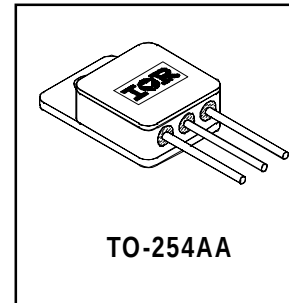
- Reduced RFI and EMI
- Reduced Snubbing
- Extensive Characterization of Recovery Parameters
- Hermetic
- Electrically Isolated
- Ceramic Eyelets



$V_R = 600V$
$V_F = 1.56V$
$Q_{rr} = 270nC$
$di_{(rec)M}/dt = 345A/\mu s$

Description

HEXFRED™ diodes are optimized to reduce losses and EMI/RFI in high frequency power conditioning systems. An extensive characterization of the recovery behavior for different values of current, temperature and di/dt simplifies the calculations of losses in the operating conditions. The softness of the recovery eliminates the need for a snubber in most applications. These devices are ideally suited for power converters, motors drives and other applications where switching losses are significant portion of the total losses.



Absolute Maximum Ratings (per Leg)

	Parameter	Max.	Units
V_R	D.C. Reverse Voltage	600	V
$I_F @ T_C = 100^\circ C$	Continuous Forward Current ①	30	A
$I_{FSM} @ T_C = 25^\circ C$	Single Pulse Forward Current ②	150	
$P_D @ T_C = 25^\circ C$	Maximum Power Dissipation	63	W
T_J T_{STG}	Operating Junction and Storage Temperature Range	-55 to +150	°C

Thermal - Mechanical Characteristics

	Parameter	Typ.	Max.	Units
$R_{\theta JC}$	Junction-to-Case, Single Leg Conducting	—	2.0	°C/W
	Weight	9.3	—	g

Note: ① D.C. = 50% rect. wave

② 1/2 sine wave, 60 Hz, P.W. = 8.33 ms

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HFA35HB60C

International
IRF Rectifier

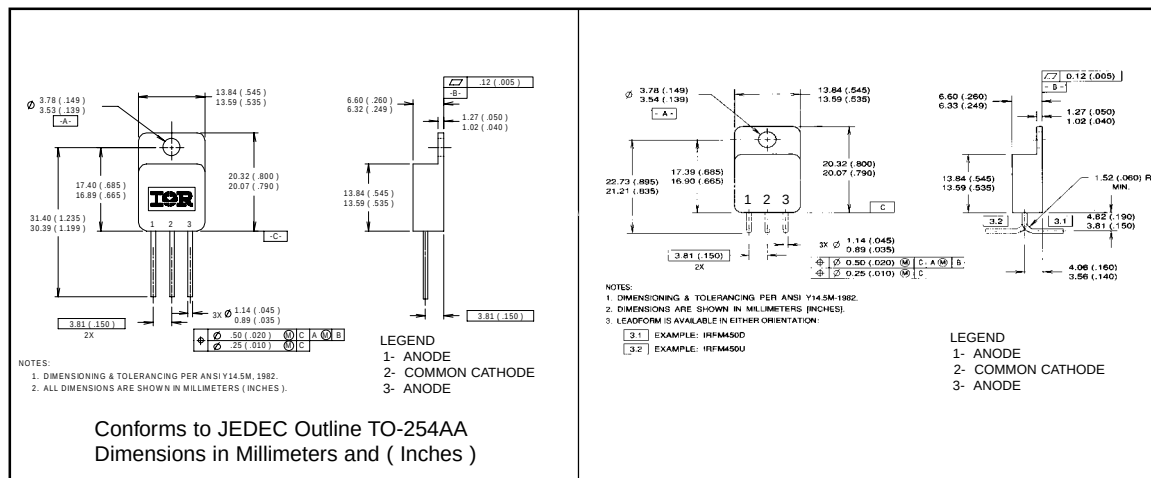
Electrical Characteristics (per Leg) @ $T_J = 25^\circ\text{C}$ (unless otherwise specified)

	Parameter	Min.	Typ.	Max.	Units	Test Conditions
V_{BR}	Cathode Anode Breakdown Voltage	600	—	—	V	$I_R = 250\mu\text{A}$
V_{FM}	Max Forward Voltage	—	—	1.56	V	$I_F = 15\text{A}$
		—	—	1.92		$I_F = 30\text{A}$ See Fig. 1
		—	—	1.51		$I_F = 15\text{A}, T_J = 125^\circ\text{C}$
I_{RM}	Max Reverse Leakage Current	—	—	10	μA	$V_R = V_R$ Rated
		—	—	1.0	mA	$T_J = 125^\circ\text{C}, V_R = 480\text{V}$ See Fig. 2
C_T	Junction Capacitance	—	24	36	pF	$V_R = 200\text{V}$ See Fig. 3
L_S	Series Inductance	—	8.7	—	nH	Measured from center of bond pad to end of anode bonding wire

Dynamic Recovery Characteristics (per Leg) @ $T_J = 25^\circ\text{C}$ (unless otherwise specified)

	Parameter	Min.	Typ.	Max.	Units	Test Conditions
t_{rr1}	Reverse Recovery Time	—	54	88	ns	$T_J = 25^\circ\text{C}$ See Fig.
t_{rr2}		—	94	140		$T_J = 125^\circ\text{C}$ 5
I_{RRM1}	Peak Recovery Current	—	5.6	7.8	A	$T_J = 25^\circ\text{C}$ See Fig.
I_{RRM2}		—	7.8	11.7		$T_J = 125^\circ\text{C}$ 6
Q_{rr1}	Reverse Recovery Charge	—	180	270	nC	$T_J = 25^\circ\text{C}$ See Fig.
Q_{rr2}		—	435	650		$T_J = 125^\circ\text{C}$ 7
$di_{(rec)M}/dt1$	Peak Rate of Fall of Recovery Current	—	300	345	$\text{A}/\mu\text{s}$	$T_J = 25^\circ\text{C}$ See Fig.
$di_{(rec)M}/dt2$		—	190	285		$T_J = 125^\circ\text{C}$ 8

Case Outline and Dimensions — TO-254AA



CAUTION

BERYLLIA WARNING PER MIL-PRF-19500

Package containing beryllia shall not be ground, sandblasted, machined, or have other operations performed on them which will produce beryllia or beryllium dust. Furthermore, beryllium oxide packages shall not be placed in acids that will produce fumes containing beryllium.

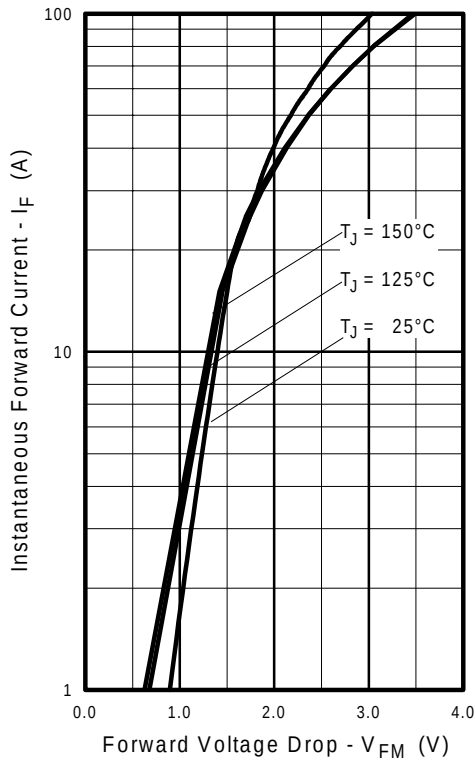


Fig. 1 - Maximum Forward Voltage Drop vs. Instantaneous Forward Current

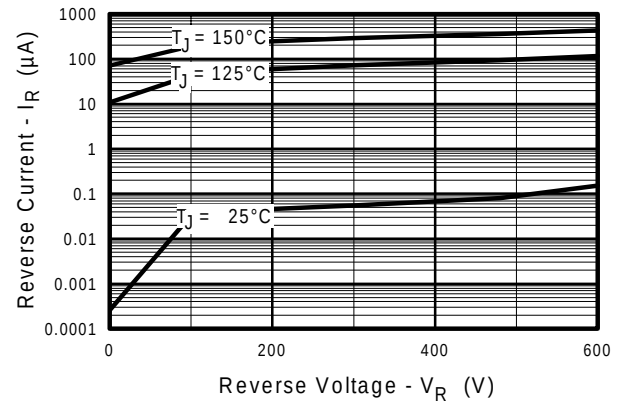


Fig. 2 - Typical Reverse Current vs. Reverse Voltage

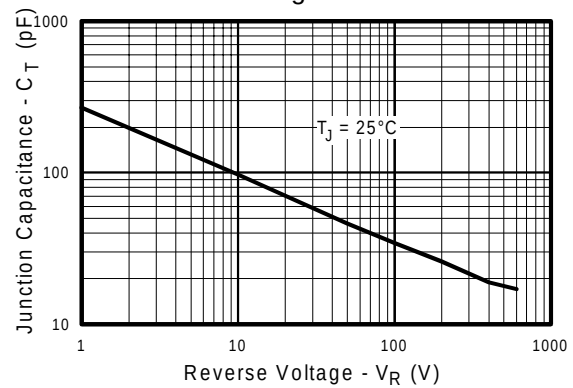


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

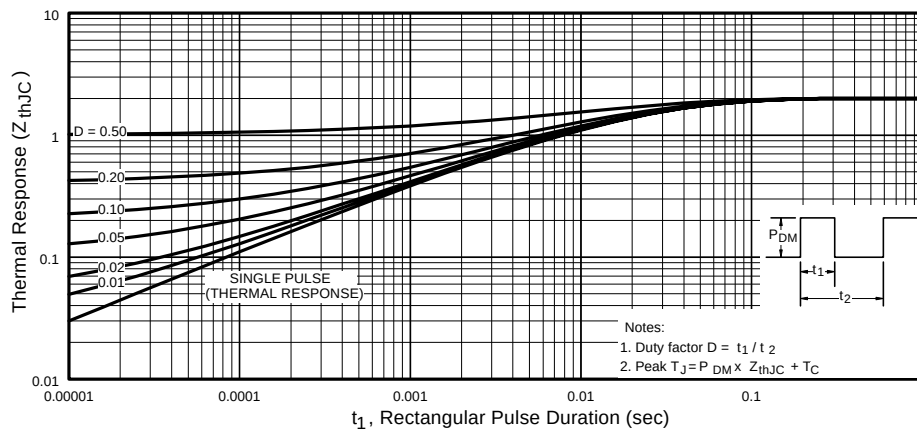


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

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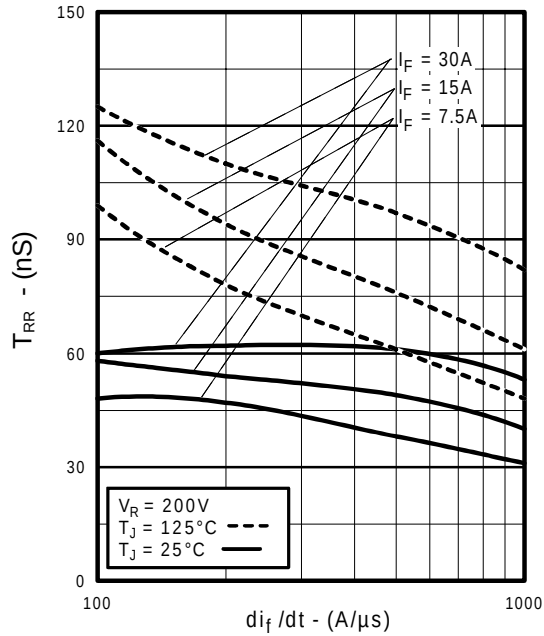


Fig. 5 - Typical Reverse Recovery vs. di_f/dt

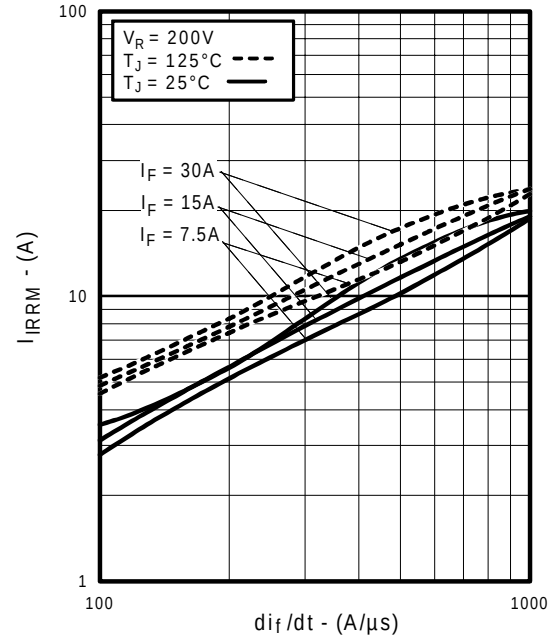


Fig. 6 - Typical Recovery Current vs. di_f/dt

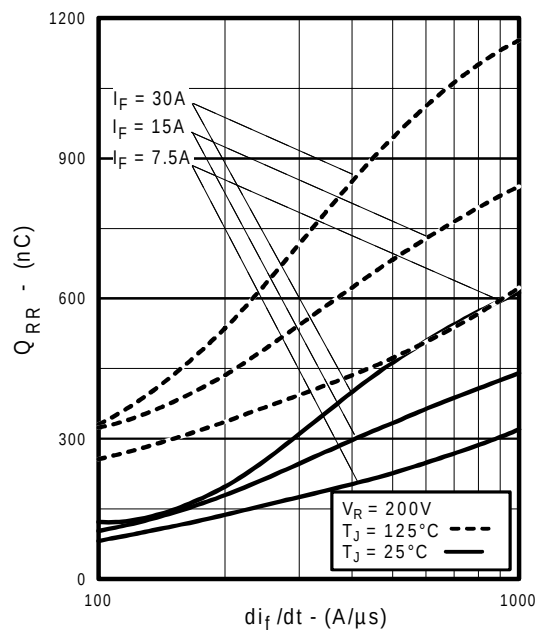


Fig. 7 - Typical Stored Charge vs. di_f/dt

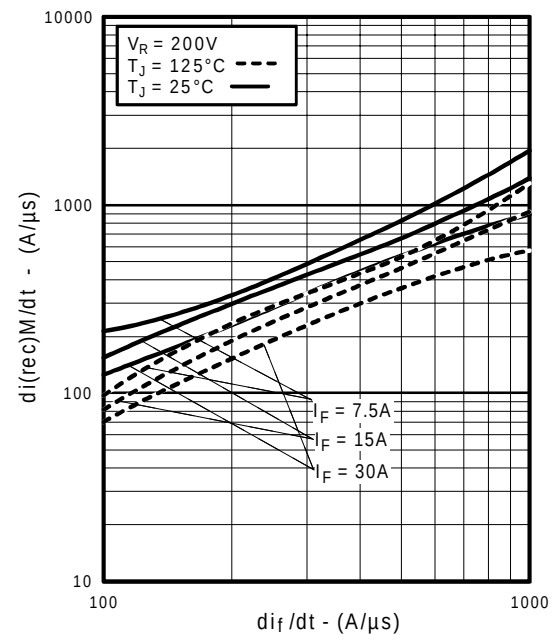


Fig. 8 - Typical $di_{(rec)M}/dt$ vs. di_f/dt

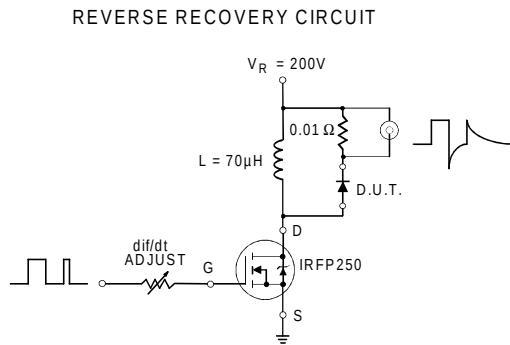


Fig. 9 - Reverse Recovery Parameter Test Circuit

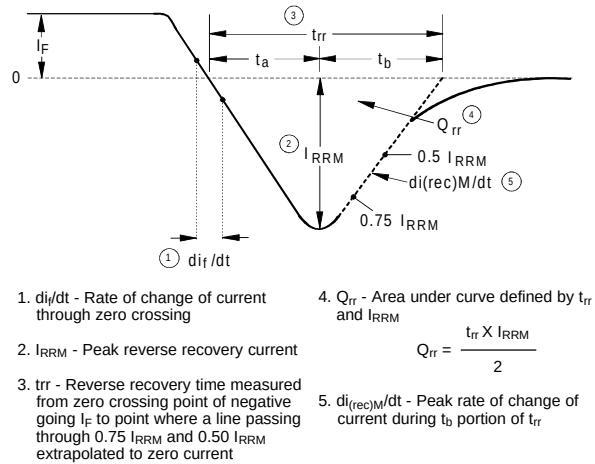


Fig. 10 - Reverse Recovery Waveform and Definitions